

JUNCTION FIELD EFFECT TRANSISTOR 2SK3653

N-CHANNEL SILICON JUNCTION FIELD EFFECT TRANSISTOR FOR IMPEDANCE CONVERTER OF ECM

DESCRIPTION

The 2SK3653 is suitable for converter of ECM.

FEATURES

- Compact package
- High forward transfer admittance
1000 μS TYP. ($I_{\text{DSS}} = 100 \mu\text{A}$)
1600 μS TYP. ($I_{\text{DSS}} = 200 \mu\text{A}$)
- Includes diode and high resistance at G - S

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK3653	3pinXSOF (0814)

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

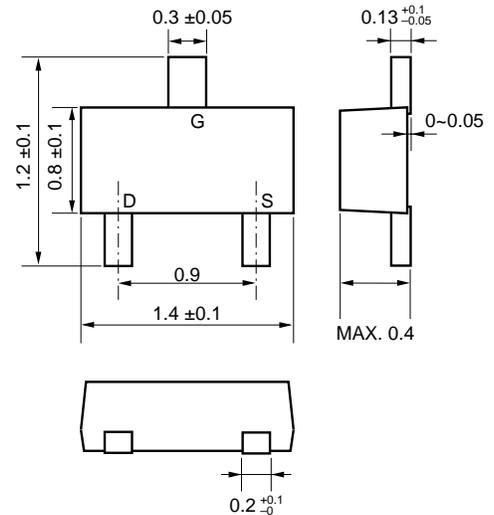
Drain to Source Voltage ^{Note1}	V_{DSX}	20	V
Gate to Drain Voltage	V_{GDO}	-20	V
Drain Current	I_{D}	10	mA
Gate Current	I_{G}	10	mA
Total Power Dissipation ^{Note2}	P_{T}	80	mW
Junction Temperature	T_{j}	125	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +125	$^\circ\text{C}$

Notes 1. $V_{\text{GS}} = -1.0 \text{ V}$

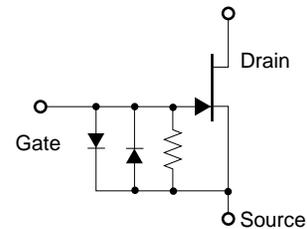
2. Mounted on ceramic substrate of $3.0 \text{ cm}^2 \times 0.64 \text{ mm}$

Remark Please take care of ESD (Electro Static Discharge) when you handle the device in this document.

PACKAGE DRAWING (Unit: mm)



EQUIVALENT CIRCUIT



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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

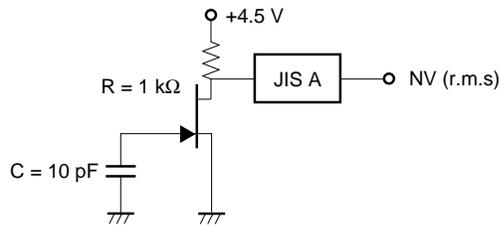
ELECTRICAL CHARACTERISTICS (T_A = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Cut-off Current	I _{DSS1}	V _{DS} = 2.0 V, V _{GS} = 0 V	38		570	μA
Zero Gate Voltage Drain Cut-off Current	I _{DSS2}	V _{DS} = 5.0 V, V _{GS} = 0 V	40		600	μA
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 5.0 V, I _D = 1.0 μA	-0.1		-1.0	V
Forward Transfer Admittance	y _{fs1}	V _{DS} = 5.0 V, I _D = 30 μA, f = 1.0 kHz	350			μS
Forward Transfer Admittance	y _{fs2}	V _{DS} = 5.0 V, V _{GS} = 0 V, f = 1.0 kHz	350			μS
Input Capacitance	C _{iss}	V _{DS} = 5.0 V, V _{GS} = 0 V, f = 1.0 MHz		7.0	8.0	pF
Noise Voltage	NV	See Test Circuit		1.8	3.0	μV

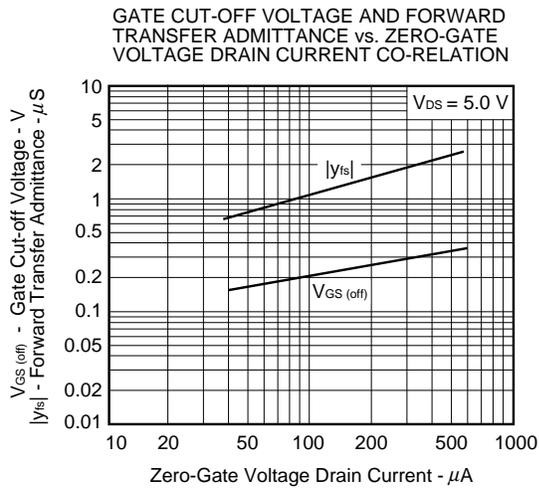
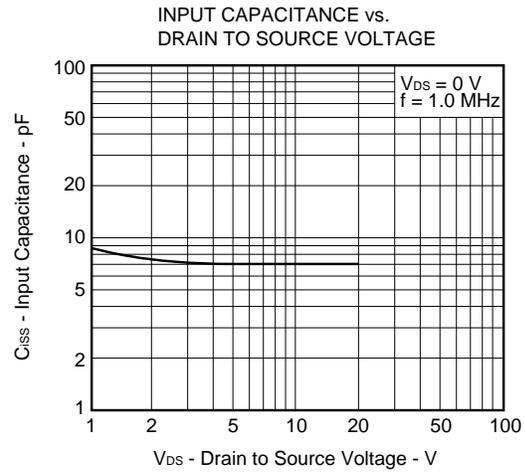
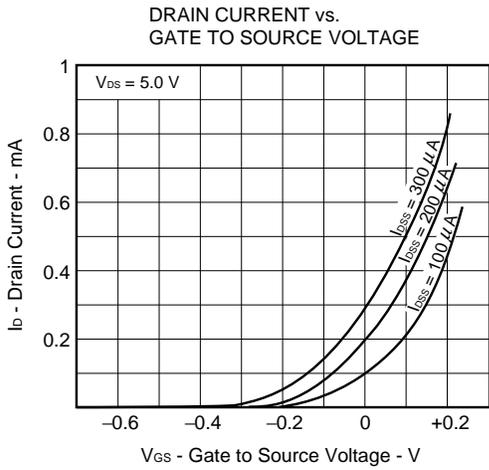
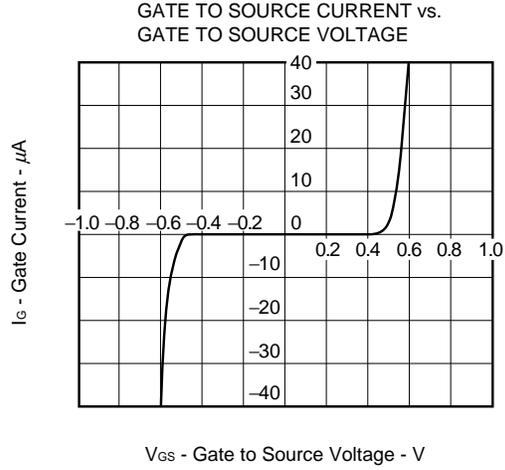
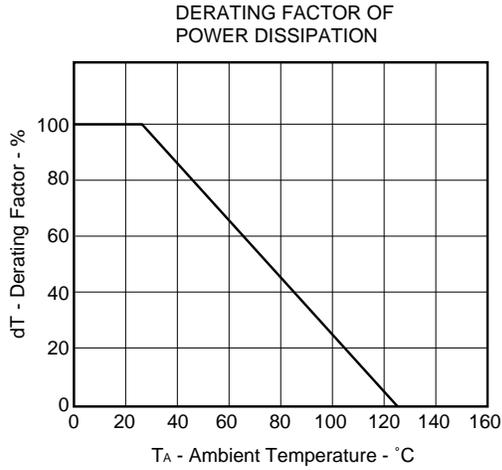
I_{DSS} RANK

MARKING	J2	J3	J4	J5	J6	J7
I _{DSS1} (μA) V _{DS} = 2.0 V	38 to 65	56 to 105	85 to 170	140 to 280	185 to 425	280 to 570

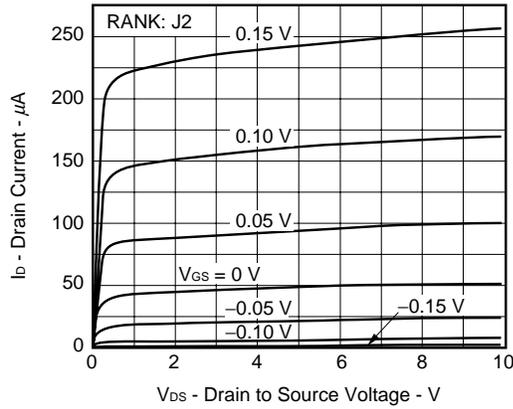
NOISE VOLTAGE TEST CIRCUIT



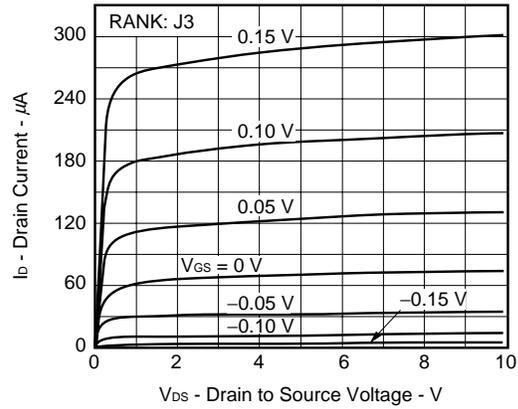
TYPICAL CHARACTERISTICS (T_A = 25°C)



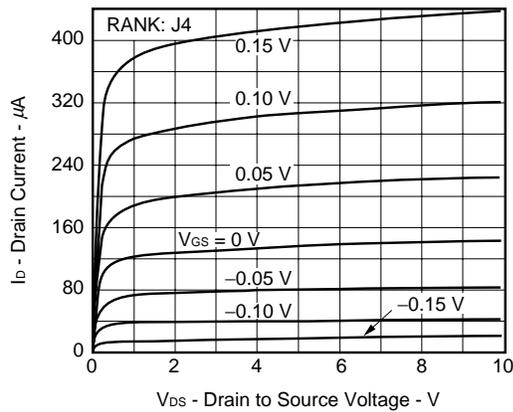
DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



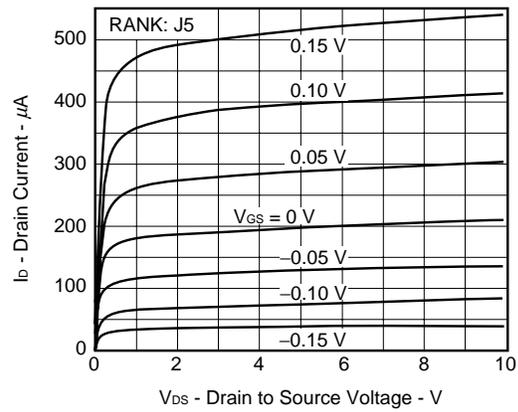
DRAIN CURRENT vs.
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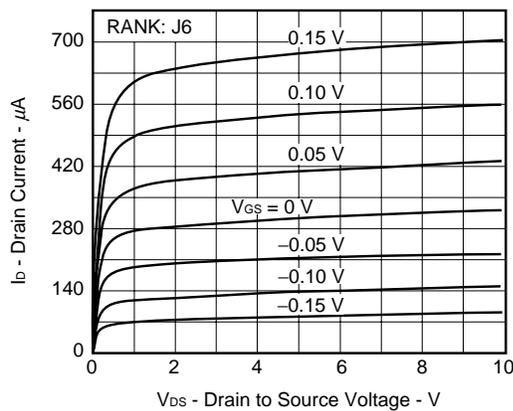
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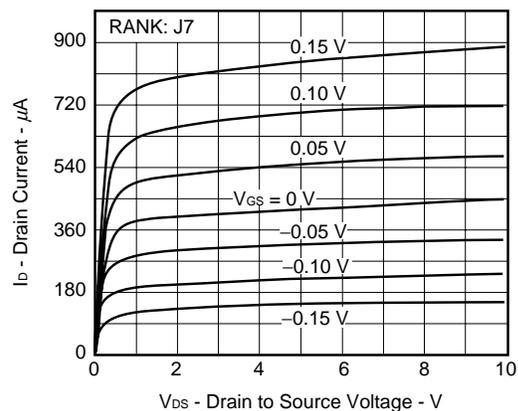
DRAIN CURRENT vs.
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DRAIN CURRENT vs.
DRAIN TO SOURCE VOLTAGE



[MEMO]

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